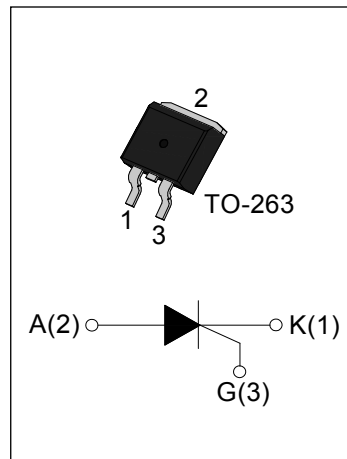




### DESCRIPTION:

With high ability to withstand the shock loading of large current, JCTx25 SCRs provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-263 is RoHS compliant. (2011/65/EU)



### MAIN FEATURES

|                   |        |        |
|-------------------|--------|--------|
| Symbol            | JCT625 | JCT825 |
| $V_{DRM}/V_{RRM}$ | 600V   | 800V   |
| $I_{T(RMS)}$      | 25A    |        |
| $I_{GT}$          | ≤40mA  |        |

### ABSOLUTE MAXIMUM RATINGS

| Parameter  | Symbol       | Value   | Unit      |
|--|--------------|---------|-----------|
| Storage junction temperature range                                     | $T_{stg}$    | -40-150 | °C        |
| Operating junction temperature range                                   | $T_j$        | -40-150 | °C        |
| Repetitive peak off-state voltage( $T_j=25^{\circ}C$ )                 | $V_{DRM}$    | 600/800 | V         |
| Repetitive peak reverse voltage( $T_j=25^{\circ}C$ )                   | $V_{RRM}$    | 600/800 | V         |
| RMS on-state current<br>TO-263<br>( $T_c=90^{\circ}C$ )                | $I_{T(RMS)}$ | 25      | A         |
| Non repetitive surge peak on-state current<br>( $t_p=10ms$ )           | $I_{TSM}$    | 300     | A         |
| $I^2t$ value for fusing ( $t_p=10ms$ )                                 | $I^2t$       | 450     | $A^2s$    |
| Critical rate of rise of on-state current<br>( $I_G=2 \times I_{GT}$ ) | $di/dt$      | 50      | $A/\mu s$ |
| Peak gate current  | $I_{GM}$     | 4       | A         |
| Average gate power dissipation   | $P_{G(AV)}$  | 1       | W         |
| Peak gate power  | $P_{GM}$     | 5       | W         |

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^{\circ}\text{C}$  unless otherwise specified)

| Symbol   | Test Condition   | Value |      |      | Unit             |
|----------|--|-------|------|------|------------------|
|          |  | MIN.  | TYP. | MAX. |                  |
| $I_{GT}$ | $V_D=12\text{V } R_L=33\Omega$                               | -     | -    | 40   | mA               |
| $V_{GT}$ |  | -     | -    | 1.3  | V                |
| $V_{GD}$ | $V_D=V_{DRM} T_j=150^{\circ}\text{C } R_L=3.3\text{K}\Omega$ | 0.2   | -    | -    | V                |
| $I_L$    | $I_G=1.2I_{GT}$  | -     | -    | 90   | mA               |
| $I_H$    | $I_T=500\text{mA}$   | -     | -    | 80   | mA               |
| dV/dt    | $V_D=2/3V_{DRM}$ Gate Open $T_j=150^{\circ}\text{C}$         | 200   | -    | -    | V/ $\mu\text{s}$ |

**STATIC CHARACTERISTICS**

| Symbol    | Parameter                               |                           | Value(MAX) | Unit          |
|-----------|---|---------------------------|------------|---------------|
| $V_{TM}$  | $I_{TM}=50\text{A } t_p=380\mu\text{s}$ | $T_j=25^{\circ}\text{C}$  | 1.55       | V             |
| $I_{DRM}$ | $V_D=V_{DRM} V_R=V_{RRM}$               | $T_j=25^{\circ}\text{C}$  | 10         | $\mu\text{A}$ |
| $I_{RRM}$ |   | $T_j=150^{\circ}\text{C}$ | 4          | mA            |

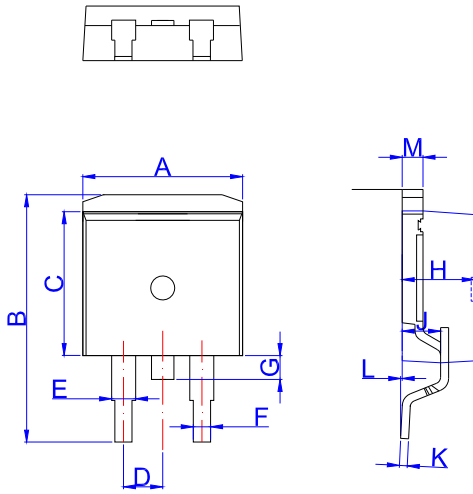
**THERMAL RESISTANCES**

| Symbol        | Parameter            |        | Value | Unit                 |
|---------------|----------------------|--------|-------|----------------------|
| $R_{th(j-c)}$ | junction to case(AC) | TO-263 | 1.9   | $^{\circ}\text{C/W}$ |
| $R_{th(j-a)}$ | junction to ambient  |        | 45    |                      |

**ORDERING INFORMATION**

|  |  |                  |                 |  |   |
|--|--|------------------|-----------------|--|---|
| <p>JieJie Microelectronics Co.,Ltd</p> | <p><b>J</b></p> <p>SCRs</p> <p>6:<math>V_{DRM} / V_{RRM} \geq 600\text{V}</math><br/>8:<math>V_{DRM} / V_{RRM} &gt; 800\text{V}</math></p> | <p><b>CT</b></p> | <p><b>6</b></p> | <p><b>25</b></p> <p><math>I_{T(RMS)}:25\text{A}</math></p> | <p><b>E</b></p> <p>E:TO-263<br/>ETR:TO-263(Tape&amp;Reel)</p> |
|--|--|------------------|-----------------|--|---|

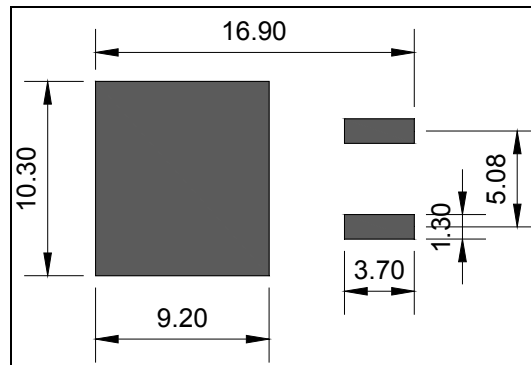
PACKAGE MECHANICAL DATA



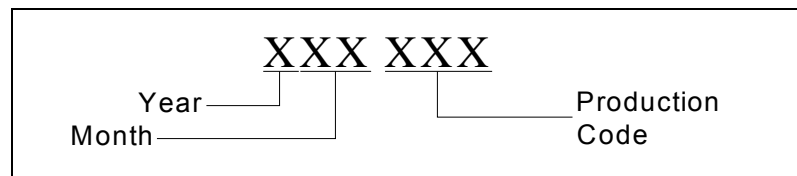
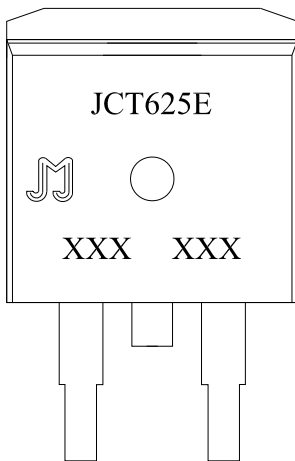
TO-263

| Ref. | Dimensions  |      |       |        |       |       |
|------|-------------|------|-------|--------|-------|-------|
|      | Millimeters |      |       | Inches |       |       |
|      | Min.        | Typ. | Max.  | Min.   | Typ.  | Max.  |
| A    | 9.90        |      | 10.20 | 0.390  |       | 0.402 |
| B    | 14.70       |      | 15.80 | 0.579  |       | 0.622 |
| C    | 9.4         |      | 9.6   | 0.37   |       | 0.378 |
| D    |             | 2.54 |       |        | 0.100 |       |
| E    | 1.20        |      | 1.40  | 0.047  |       | 0.055 |
| F    | 0.75        |      | 0.85  | 0.029  |       | 0.033 |
| G    |             |      | 1.75  |        |       | 0.069 |
| H    | 4.40        |      | 4.70  | 0.173  |       | 0.185 |
| J    | 2.30        |      | 2.70  | 0.091  |       | 0.106 |
| K    | 0.38        |      | 0.55  | 0.015  |       | 0.022 |
| L    | 0           | 0.10 | 0.25  | 0      | 0.004 | 0.010 |
| M    | 1.25        |      | 1.35  | 0.049  |       | 0.053 |

FOOTPRINT-TO-263 (dimensions in mm)



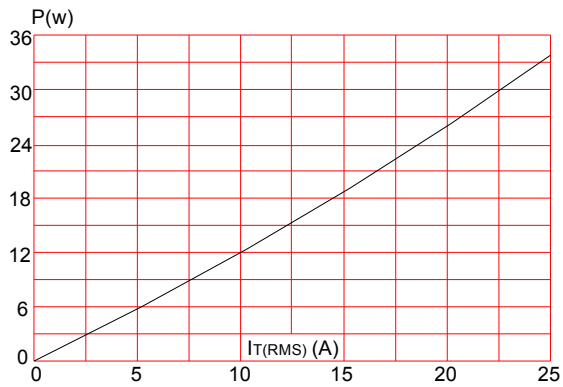
MARKING



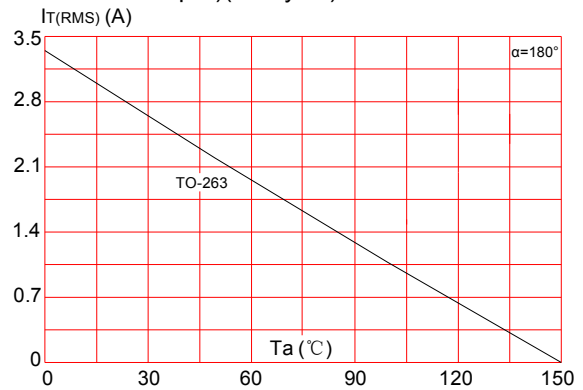
PACKAGE INFORMATION

| PACKAGE | OUTLINE | TUBE (PCS) | INNER BOX (PCS)  | PER CARTON  |
|---------|---------|------------|------------------|-------------|
| TO-263  | TUBE    | 50         | 1,000            | 6,000       |
| TO-263  | TUBE    | 50         | 1,000            | 8,000       |
| PACKAGE | OUTLINE | REEL (PCS) | PER CARTON (PCS) | TAPE & REEL |
| TO-263  | TAPING  | 800        | 4,000            | 13 inch     |

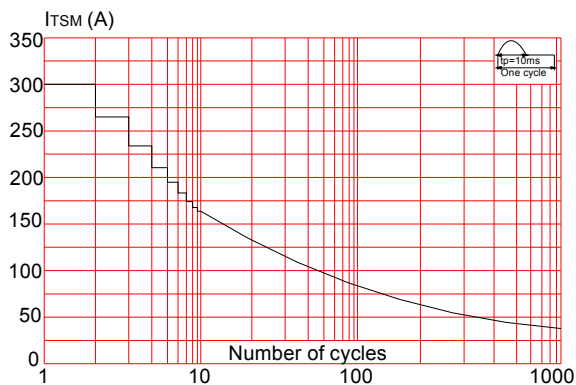
**FIG.1:** Maximum power dissipation versus RMS on-state current



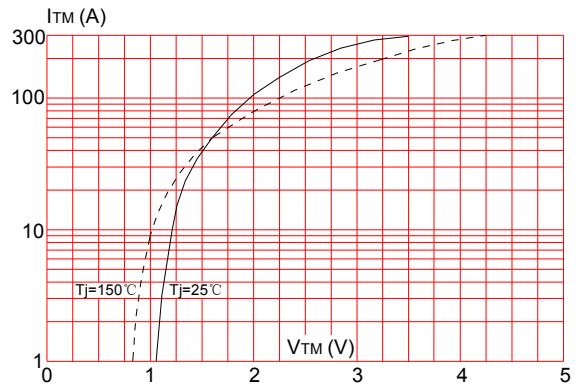
**FIG.2:** RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:35μm)(full cycle)



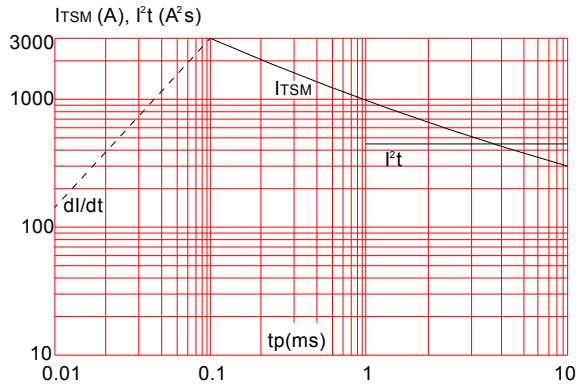
**FIG.3:** Surge peak on-state current versus number of cycles



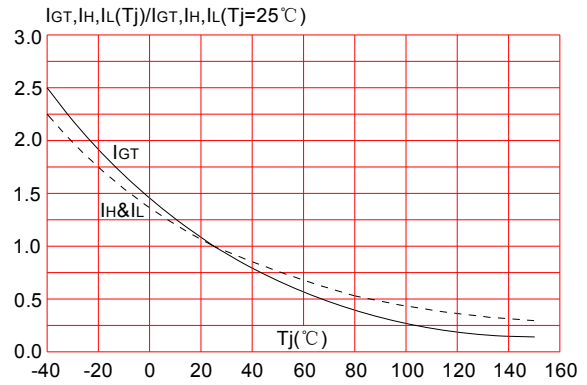
**FIG.4:** On-state characteristics (maximum values)



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 50\text{A}/\mu\text{s}$ )

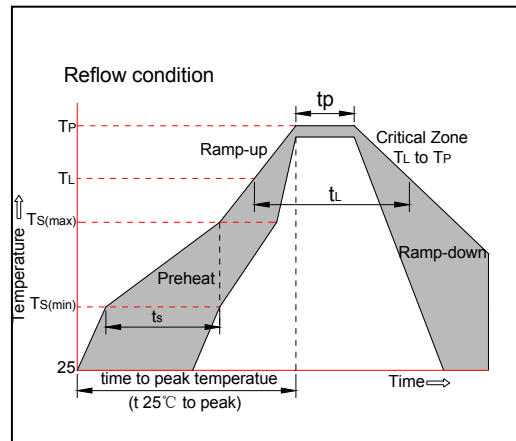


**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature




**SOLDERING PARAMETERS**

|  |  |   |
|--|--|---|
| Reflow Condition   |  | Pb-Free assembly<br>(see figure at right) |
| Pre Heat   | -Temperature Min ( $T_{s(\text{min})}$ ) | +150 $^\circ\text{C}$                     |
|  | -Temperature Max ( $T_{s(\text{max})}$ ) | +200 $^\circ\text{C}$                     |
|  | -Time (Min to Max) ( $t_s$ )             | 60-180 secs.                              |
| Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)       |  | 3 $^\circ\text{C}/\text{sec.}$ Max        |
| $T_{s(\text{max})}$ to $T_L$ - Ramp-up Rate                  |  | 3 $^\circ\text{C}/\text{sec.}$ Max        |
| Reflow   | -Temperature ( $T_L$ ) (Liquidus)        | +217 $^\circ\text{C}$                     |
|  | -Temperature ( $t_L$ )                   | 60-150 secs.                              |
| Peak Temp ( $T_p$ )  |  | +260(+0/-5) $^\circ\text{C}$              |
| Time within 5 $^\circ\text{C}$ of actual Peak Temp ( $t_p$ ) |  | 20-40secs.                                |
| Ramp-down Rate   |  | 6 $^\circ\text{C}/\text{sec.}$ Max        |
| Time 25 $^\circ\text{C}$ to Peak Temp ( $T_p$ )              |  | 8 min. Max                                |
| Do not exceed  |  | +260 $^\circ\text{C}$                     |



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